



Product Summary

BV _{DSS}	Rds(on)	ID @TA = +25°C
20)/	0.9Ω @ V _{GS} = -10V	-0.62A
-30V	1.7Ω @ V _{GS} = -4.5V	-0.45A

Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- Motor controls
- Power management functions
- DC-DC converters

DUAL P-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An automotive-compliant part is available under separate datasheet (DMP31D7LVQ)

Mechanical Data

• Package: SOT563

D1

- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)





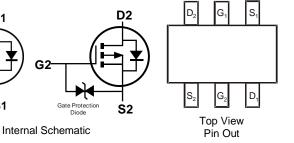
Top View

SOT563



Bottom View

G



Ordering Information (Note 4)

Part Number	Baakaga	Packing		
Fait Nulliper	Package	Qty.	Carrier	
DMP31D7LV-7	SOT563	3000	Tape & Reel	
DMP31D7LV-13	SOT563	10,000	Tape & Reel	

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Haloger- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

HC)9	Y	'M	

HD9 = Product Type Marking Code YM or \overline{Y} M= Date Code Marking Y or \overline{Y} = Year (ex: K = 2023) M = Month (ex: 9 = September)

Date Code Key

Notes:

Year	2019		2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	G		К	L	М	Ν	0	Р	R	S	Т	U
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	C		Symbol	Value	Unit
Drain-Source Voltage			VDSS	-30	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current (Note 6) V _{GS} = -4.5V	lo	-0.62 -0.5	A		
Maximum Continuous Body Diode Forward Current (ls	-0.38	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			Ідм	-2.4	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	0.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	236	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	0.8	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Rəja	153	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

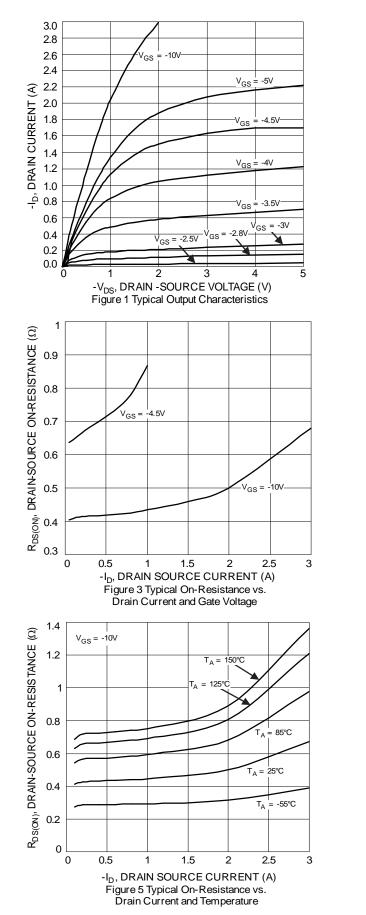
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

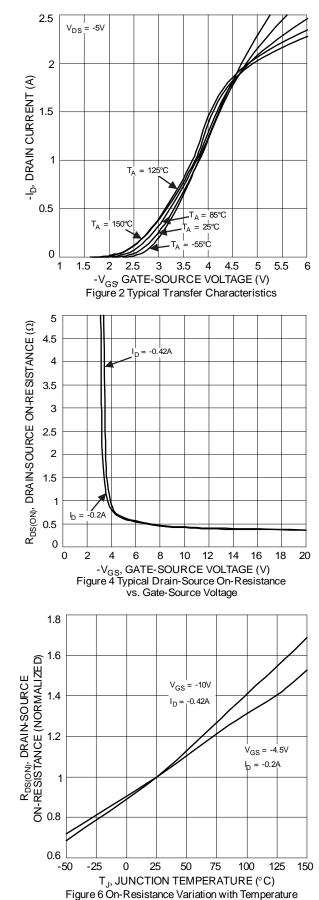
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage		BVDSS	-30			V	$V_{GS} = 0V, I_{D} = -250 \mu A$
Zero Gate Voltage Drain Current	@Tc= +25°C	IDSS			-1	μA	V _{DS} = -24V, V _{GS} = 0V
Gate-Source Leakage		lgss			±10	μA	$V_{GS} = \pm 16V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage		Vgs(th)	-1	-2.0	-2.6	V	V _{DS} = V _{GS} , I _D = -250µA
Ctatia Drain Course On Desistance			_	0.4	0.9	Ω	VGS = -10V, ID = -0.42A
Static Drain-Source On-Resistance		RDS(ON)	_	0.7	1.7	Ω	Vgs = -4.5V, ID = -0.2A
Diode Forward Voltage (Note 7)		V _{SD}	—	-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -0.23A$
DYNAMIC CHARACTERISTICS (Note	8)						
Input Capacitance		Ciss		19		pF	
Output Capacitance		Coss		16		pF	V _{DS} = -15V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance		Crss		3		pF	
Gate Resistance		Rg		729	_	Ω	V _{DS} = V _{GS} = 0V, f = 1.0MHz
Total Gate Charge (V _{GS} = -4.5V)		Qg	_	0.36		nC	
Total Gate Charge (V _{GS} = -10V)		Qg	_	0.8	_	nC	
Gate-Source Charge		Qgs		0.1		nC	VDS = -10V, ID = -0.24A
Gate-Drain Charge		Qgd		0.1	_	nC	1
Turn-On Delay Time		t _{D(ON)}	_	30		ns	
Turn-On Rise Time		t _R		74		ns	$V_{GS} = -10V, V_{DD} = -15V,$
Turn-Off Delay Time		tD(OFF)	—	28	—	ns	I _D = -0.5A, R _G = 1Ω
Turn-Off Fall Time		tF	_	31	_	ns	

Notes:

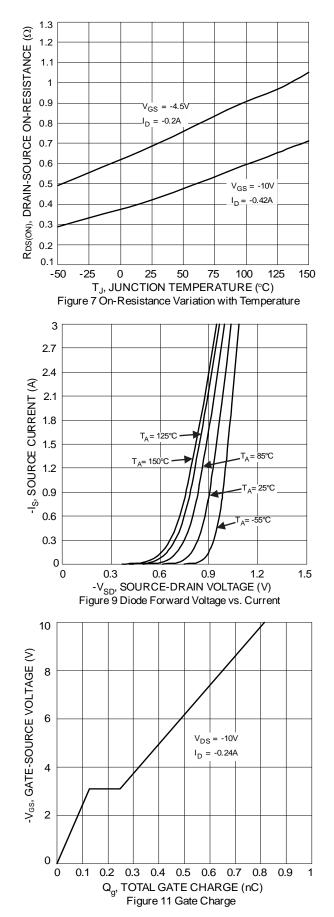
Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.

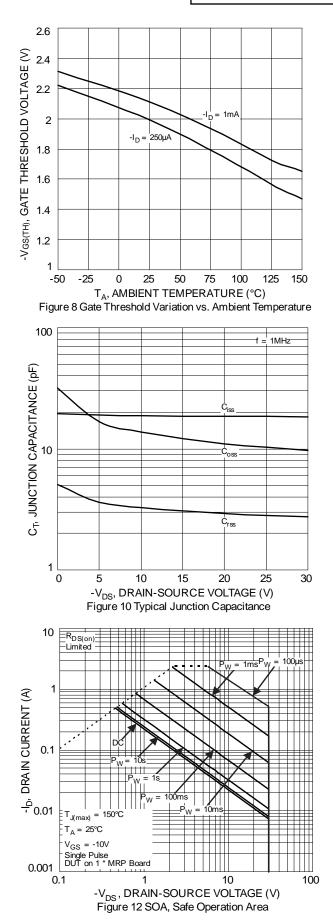






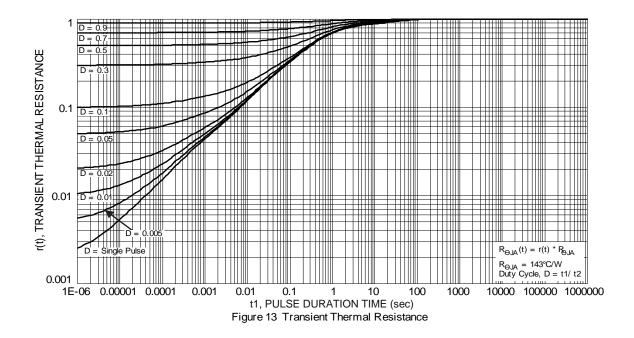






DMP31D7LV Document number: DS41782 Rev. 5 - 2

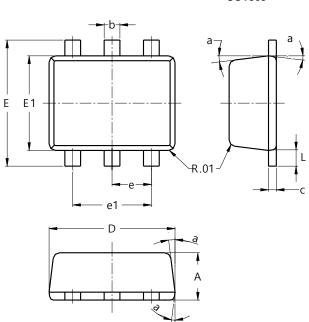






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

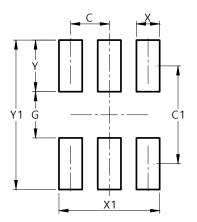


SOT563								
Dim	Min	Max	Тур					
Α	0.55	0.60						
b	0.15	0.30	0.20					
С	0.10	0.18	0.11					
D	1.50	1.70	1.60					
Е	1.55	1.70	1.60					
E1	1.10	1.25	1.20					
е			0.50					
e1	0.90	1.10	1.00					
L	0.10	0.30	0.20					
а	8°	9°	7°					
All	Dimens	sions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT563



Dimensions	Value (in mm)
С	0.500
C1	1.270
G	0.600
Х	0.300
X1	1.300
Y	0.670
Y1	1.940

SOT563



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